## SGSF664

## FASTSWITCH HOLLOW-EMITTER NPN TRANSISTOR

- HIGH SWITCHING SPEED NPN POWER TRANSISTOR
- HOLLOW EMITTER TECHNOLOGY
- HIGH VOLTAGE FOR OFF-LINE APPLICATIONS
- 50 kHz SWITCHING SPEED
- LOW COST DRIVE CIRCUITS
- LOW DYNAMIC SATURATION


## APPLICATIONS

- SMPS
- TV AND MONITOR DEFLECTION


## DESCRIPTION

This hollow emitter FASTSWITCH NPN power :ransistor is specially designed for 220 V (and 117 V with input doubler) off-line switching power supply applications. It can also be used for 117 V three
phase mains off-line switching power supplies. Hollow emitter transistors can operate at up to 50 kHz with simple drive circuits which helps to simplify design and improve reliability. The superior switching performance reduces dissipation and consequently lowers the equipment operating temperature. This transistor is suitable for applications in half bridge and full bridge high power converters, 900W to 1800W. The high switching speed of this transistor together with its high voltage and current rating, make it ideal for horizontal deflection circuits in large screen colour televisions and monitors. When used in conjunction with a low voltage Power MOSFET in emitter switch configuration, they can operate at up to 100 kHz .

This hollow emitter FASTSWITCH transistor is available in the metal can TO-3 package.
$\square$

## ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | SGSF664 | Unit |
| :---: | :--- | :---: | :---: |
| $V_{C E S}$ | Collector - Emitter Voltage $\left(\mathrm{V}_{\mathrm{BE}}=0\right)$ | 1200 | V |
| $\mathrm{~V}_{\mathrm{CEO}}$ | Collector - Emitter Voltage $\left(\mathrm{I}_{\mathrm{B}}=0\right)$ | 600 | V |
| $\mathrm{~V}_{\mathrm{EBO}}$ | Emitter - Base Voltage $\left(\mathrm{I}_{\mathrm{C}}=0\right)$ | 7 | V |
| $\mathrm{I}_{\mathrm{C}}$ | Collector Current | 20 | A |
| $\mathrm{I}_{\mathrm{CM}}$ | Collector Peak Current $\left(\mathrm{t}_{\mathrm{p}}<5 \mathrm{~ms}\right)$ | 30 | A |
| $\mathrm{I}_{\mathrm{B}}$ | Base Current | 14 | A |
| $\mathrm{I}_{\mathrm{BM}}$ | Base Peak Current $\left(\mathrm{t}_{p}<5 \mathrm{~ms}\right)$ | 24 | A |
| $\mathrm{P}_{\text {tot }}$ | Total Dissipation at $\mathrm{T} \leq 25^{\circ} \mathrm{C}$ | 250 | W |
| $\mathrm{~T}_{\text {stg }}$ | Storage Temperature -65 to | 175 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{i}}$ | Junction Temperature | 175 | ${ }^{\circ} \mathrm{C}$ |

THERMAL DATA

| F $_{\text {trj-case }}$ | Thermal Resistance Junction-case | Max | 0.6 | "C/W |
| :--- | :--- | :--- | :--- | :--- |

ELECTRICAL CHARACTERISTICS ( $T_{\text {case }}=25^{\circ} \mathrm{C}$ unless otherwise specified)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ICes | Collector Cutoff Current $\left(V_{B E}=0\right)$ | $V_{C E}=1200 \mathrm{~V}$ |  |  | 400 | $\mu \mathrm{A}$ |
| ICEO | Collector Cutoff Current $\left(I_{B}=0\right)$ | $\begin{aligned} & V_{C E}=380 \mathrm{~V} \\ & V_{C E}=600 \mathrm{~V} \end{aligned}$ |  |  | $\begin{gathered} 400 \\ 4 \end{gathered}$ | $\begin{aligned} & \mathrm{uA} \\ & \mathrm{~mA} \end{aligned}$ |
| IEbo | Emitter Cutoff Current ( $\mathrm{I}_{\mathrm{C}}=0$ ) | $V_{E B}=7 \mathrm{~V}$ |  |  | 2 | mA |
| $\mathrm{V}_{\text {CEO }}$ (sus) ${ }^{\text {. }}$ | Collector Emitter Sustaining Voltage | $\mathrm{I}_{\mathrm{C}}=0.2 \mathrm{~A}$ | 600 |  |  | V |
| $V_{C E}$ (sat)* | Collector Emitter Saturation Voltage | $\begin{array}{ll} I_{C}=12 \mathrm{~A} & \mathrm{I}_{\mathrm{B}}=2.4 \mathrm{~A} \\ \mathrm{I}_{\mathrm{C}}=7 \mathrm{~A} & \mathrm{I}_{\mathrm{B}}=1 \mathrm{~A} \end{array}$ |  |  | $\begin{aligned} & 1.5 \\ & 1.5 \\ & \hline \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $V_{B E \text { (sat) }}$. | Base Emitter Saturation Voltage | $\begin{array}{ll} I_{C}=12 A & I_{B}=2.4 A \\ I_{C}=7 A & I_{B}=1 A \end{array}$ |  |  | $\begin{aligned} & 1.5 \\ & 1.5 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |

## RESISTIVE LOAD

| Symbol | Parameter | Test Conditions |  | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| ton | Turn-on Time | $\begin{aligned} & I_{C}=12 \mathrm{~A} \\ & I_{B_{1}}=2.4 \mathrm{~A} \end{aligned}$ | $\begin{aligned} & V_{C C}=250 \mathrm{~V} \\ & I_{B 2}=-2 I_{B 1} \end{aligned}$ |  | 0.6 | 1.2 | $\mu \mathrm{s}$ |
| $t_{s}$ | Storage Time |  |  |  | 2.45 | 3.5 | $\mu \mathrm{s}$ |
| $t_{1}$ | Fall Time |  |  |  | 0.12 | 0.4 | $\mu \mathrm{s}$ |
| ton | Turn-on Time | $\begin{array}{ll} I_{C}=12 \mathrm{~A} & V_{C C}=250 \mathrm{~V} \\ I_{B 1}=2.4 \mathrm{~A} & I_{\mathrm{B} 2}=-2 I_{\mathrm{B} 1} \\ \text { with Antisaturation Network } \end{array}$ |  |  | 0.6 |  | $\mu \mathrm{s}$ |
| $t_{s}$ | Storage Time |  |  |  | 1.7 |  | $\mu \mathrm{s}$ |
| $t_{1}$ | Fall Time |  |  |  | 0.12 |  | $\mu \mathrm{s}$ |
| $t_{0 n}$ | Turn-on Time | $\begin{aligned} & I_{C}=12 \mathrm{~A} \\ & I_{B_{1}}=2.4 \mathrm{~A} \end{aligned}$ | $\begin{aligned} & V_{\mathrm{CC}}=250 \mathrm{~V} \\ & V_{\mathrm{BE}(\mathrm{ofi})}=-5 \mathrm{~V} \end{aligned}$ |  | 0.6 |  | $\mu \mathrm{s}$ |
| $t_{s}$ | Storage Time |  |  |  | 1.3 |  | $\mu \mathrm{s}$ |
| $t_{\text {f }}$ | Fall Time |  |  |  | 0.2 |  | $\mu \mathrm{s}$ |

INDUCTIVE LOAD

| Symbol | Parameter | Test Conditions |  | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $t_{5}$ | Storage Time | $\begin{aligned} & I_{C}=12 \mathrm{~A} \\ & V_{C L}=450 \mathrm{~V} \\ & \mathrm{~L}=300 \mu \mathrm{H} \end{aligned}$ | $\begin{aligned} & h_{F E}=5 \\ & V_{B E(\text { ofl })}=-5 V \\ & R_{B(0 f l)}=0.5 \Omega \end{aligned}$ |  | 1.5 | 3 | $\mu \mathrm{s}$ |
| 1. | Fall Time |  |  |  | 0.12 | 0.25 | us |
| ts | Storage Time | $\begin{aligned} & I_{C}=12 \mathrm{~A} \\ & V_{C L}=450 \mathrm{~V} \\ & L=300 \mu \mathrm{H} \\ & T_{C}=100^{\circ} \mathrm{C} \end{aligned}$ | $n_{F E}=5$ <br> $V_{B E \text { (olf) }}=-5 \mathrm{~V}$ <br> $R_{\mathrm{B}(011)}=0.5 \mathrm{~S} 2$ |  |  | 4.3 | $\mu \mathrm{S}$ |
| $t_{1}$ | Fall Time |  |  |  |  | 0.35 | $\mu \mathrm{s}$ |

[^0]Safe Operating Areas


DC Current Gain


Collector-emitter Saturation Voltage


Reverse Biased Safe Operating Area


Collector-emitter Saturation Voltage


Base-emitter Saturation Voltage


Resistive Load Switching Times


Switching Times Percentance Variation


Inductive Load Switching Times



[^0]:    Pulsed Pulse duration $=300 \mu \mathrm{~s}$. duty cycle $=1.5 \%$

